#### **Application Data Sheet**

#### **Application Information**

Application number::

Filing Date::

Application Type::

Subject Matter::

Title ::

Regular

Utility

**BEAM IRRADIATION** 

APPARATUS, BEAM

IRRADIATION METHOD,

AND METHOD FOR

MANUFACTURING THIN

FILM TRANSISTOR

Attorney Docket Number::

0756-7295

**Total Drawing Sheets::** 

5

Small Entity?::

No

### **Applicant Information**

Applicant Authority Type::

Inventor

Primary Citizenship Country::

Japan

Given Name::

Koichiro

Middle Name::

Family Name::

**TANAKA** 

Name Suffix::

City of Residence::

Atsugi

State or Province of Residence::

Kanagawa

Country of Residence::

Japan

Street of mailing address:: c/o Semiconductor Energy

Laboratory Co., Ltd.

398, Hase

City of mailing address:: Atsugi-shi

State or Province of mailing address:: Kanagawa-ken

Country of mailing address:: Japan

Postal or Zip Code of mailing address:: 243-0036

#### **Correspondence Information**

Correspondence Customer Number :: 31780

E-Mail address:: erobinson@riplo.com

#### Representative Information

Representative Customer Number:: 31780

## **Domestic Priority Information**

App	lication ::	Continuity Type::	Parent Application::	Parent Filing Date::

# Foreign Priority Information

Country::	Application number::	Filing Date::	Priority Claimed::
Japan	2003-116392	04/21/2003	Yes

# Assignee Information

Assignee name:: Semiconductor Energy

Laboratory Co., Ltd.

Street of mailing address:: 398 Hase

City of mailing address:: Atsugi-shi

State or Province of mailing address:: Kanagawa-ken

Country of mailing address:: Japan

Postal or Zip Code of mailing address:: 243-0036